TOSHIBA GTR Module Silicon N Channel IGBT

MG50Q1ZS50

High Power Switching Applications Motor Control Applications

• High input impedance

• High speed : $t_f = 0.3 \mu s$ (Max)

@Inductive load

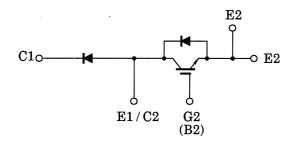
• Low saturation voltage

: VCE (sat) = 3.6 V (Max)

• Enhancement-mode

• The electrodes are isolated from case.

Equivalent Circuit



Maximum Ratings (Ta = 25°C)

			Unit: n	nm
JAPAN J	3-M5 23±0.5 23±0.5 80±0.3 93.5±0.5	B2 E2	AST-ON-TAB # 110 2-\$5.6±0.3 4 + 0.6 9 0 + 1 10.6 9 0 + 1 10.6 9 0 + 1 10.6 10.6 10.6 10.6 10.6 10.6 10.6 10.	
±81 ±81 ±81 ±81 ±81 ±81 ±81 ±81 ±81 ±81	4±0.5 4±0.5 0.5 19±0.5 18	9.9±0.8 ±0.5	27±0.5	3.0±0.5
JEDEC		_		
EIAJ				
TOSHIBA		2-94D7	4	
Weight: 202				

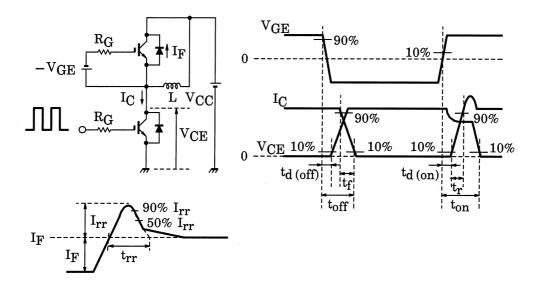
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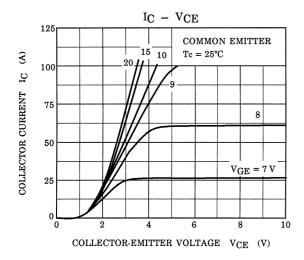
Characteristic		Symbol	Rating	Unit	
Collector-emitter voltage		V _{CES}	1200	V	
Gate-emitter voltage		V _{GES}	±20	V	
Collector current	DC	I _C (25°C / 80°C)	78 / 50	A	
Collector current	1ms	I _{CP} (25°C / 80°C)	156 / 100		
Forward current	DC	l _F	50	Α	
Forward current	1ms	I _{FM}	100	A	
Collector power dissipation (PC	400	W		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	− 40 ~ 125	°C	
Isolation voltage		V _{Isol}	2500 (AC 1 minute)	V	
Screw torque (Terminal / mounting)		_	- 3/3		

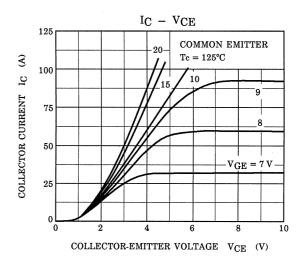
Electrical Characteristics (Ta = 25°C)

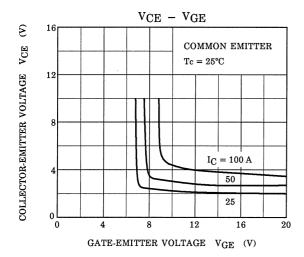
Characteristic		Symbol	Test Condition		Min	Тур.	Max	Unit
Gate leakage current		I _{GES}	V _{GE} = ±20V, V _{CE} = 0		_	_	±500	nA
Collector cut-off current		I _{CES}	V _{CE} = 1200V, V _{GE} = 0		_	_	1.0	mA
Gate-emitter cut-off voltage		V _{GE (off)}	I _C = 50mA, V _{CE} = 5V		3.0	_	6.0	V
Collector-emitter saturation voltage		V _{CE} (sat)	I _C = 50A, V _{GE} = 15V	T _j = 25°C	_	2.8	3.6	V
				T _j = 125°C	_	3.1	4.0	
Input capacitance		C _{ies}	V _{CE} = 10V, V _{GE} = 0, f = 1MHz		_	6.0	_	nF
	Turn-on delay time	t _{d (on)}			_	0.05	_	
Switching time	Rise time	t _r	Inductive load V_{CC} = 600 V I_{C} = 50 A V_{GE} = ±15 V I_{C} = 24 I_{C}	•	_	0.05	_	μs
	Turn-on time	t _{on}		•	_	0.2	_	
	Turn-off delay time	t _{d (off)}		•	_	0.5	_	
	Fall time	t _f		(Note 1)	_	0.1	0.3	
	Turn-off time	t _{off}		•	_	0.6	_	
Forward voltage		V _F	I _F = 50 A, V _{GE} = 0		_	2.4	3.5	V
Reverse recovery time		t _{rr}	$I_F = 50 \text{ A}, V_{GE} = -10 \text{ V},$ di / dt = 700 A / μ s (Note 1)		_	0.1	0.25	μs
Thermal resistance		R _{th (j-c)}	Transistor stage		_	_	0.31	°C/W
			Diode stage		_	_	0.94	

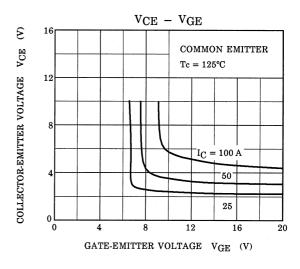
Note 1: Switching time and reverse recovery time test circuit & timing chart

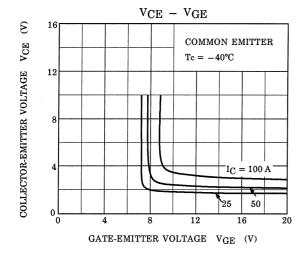


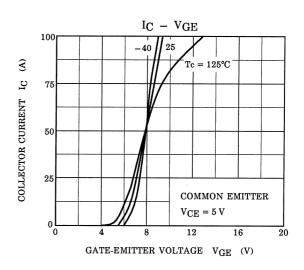


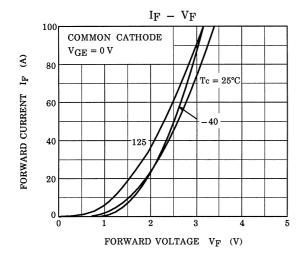


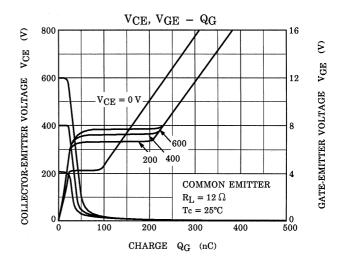


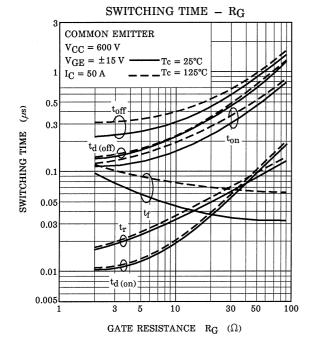


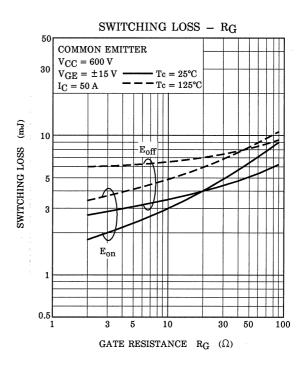


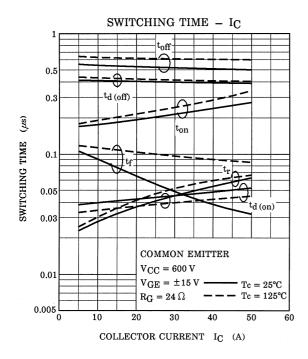


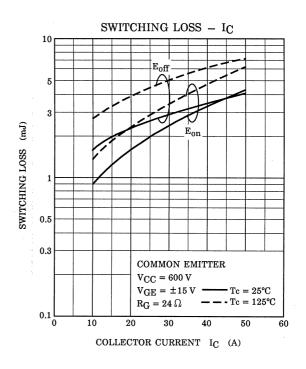


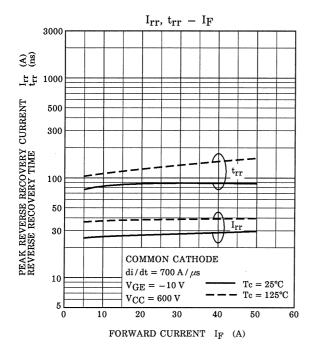


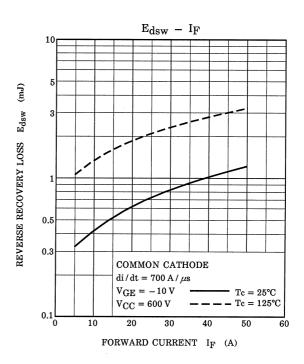


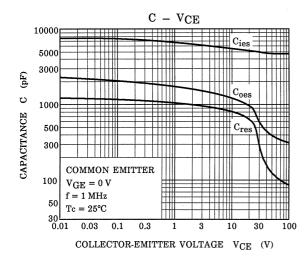


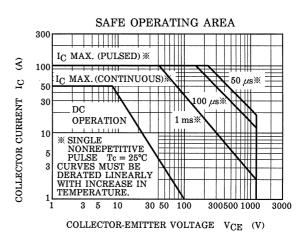


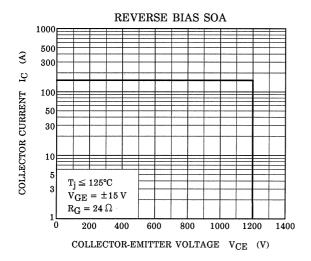


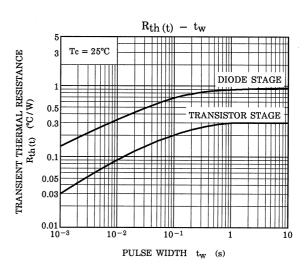


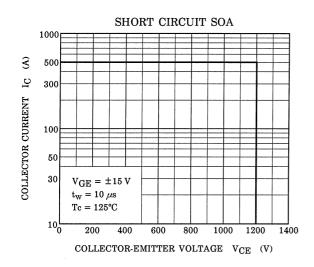












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